National Semiconductor

LM2002/LM2002A 8 Watt Audio Power Amplifier

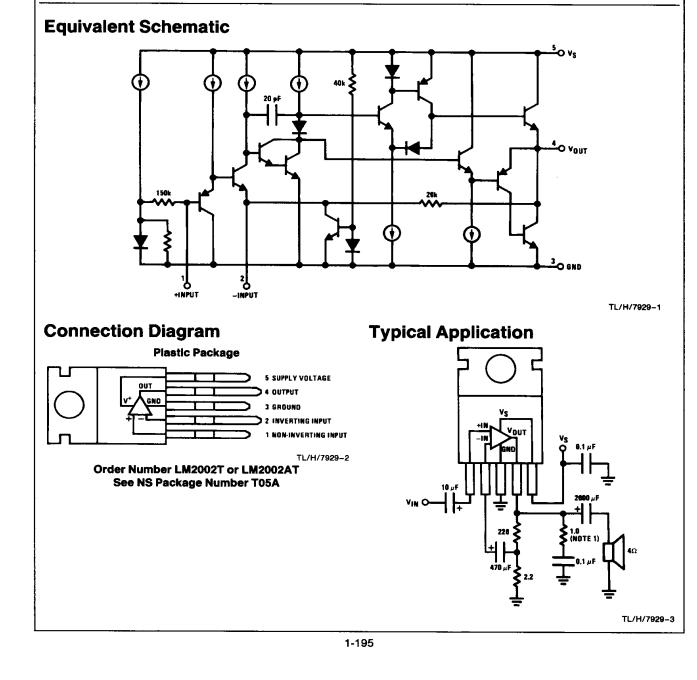
General Description

The LM2002 is a cost effective, high power amplifier suited for automotive applications. High current capability (3.5A) enables the device to drive low impedance loads with low distortion. The LM2002 is current limited and thermally protected. High voltage protection is available (LM2002A) which enables the amplifier to withstand 40V transients on its supply. The LM2002 comes in a 5-pin TO-220 package.

Features

- High peak current capability (3.5A)
- Large output voltage swing

- Externally programmable gain
- Wide supply voltage range (5V-20V)
- Few external parts required
- Low distortion
- High input impedance
- No turn-on transients
- High voltage protection available (LM2002A)
- Low noise
- AC short circuit protected
- Pin for pin compatible with TDA2002



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Absolute Maximum Ratings

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

Office/Distributors for availability and specifications. Peak Supply Voltage (50 ms)		Repetitive	3.5A
		Non-repetitive	4.5A
LM2002A (Note 2)	40V	Input Voltage	±0.5V
LM2002	25V	Power Dissipation (Note 3)	15W
Operating Supply Voltage	20V	Operating Temperature	0°C to + 70°C
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Output Current

Storage Temperature-60°C to +150°CLead Temperature (Soldering, 10 sec.)260°C

Electrical Characteristics

 $V_S = 14.4V$, $T_{TAB} = 25^{\circ}$ C, $A_V = 100$ (40 dB), $R_L = 4\Omega$, unless otherwise specified

Parameter	Conditions	Min	Тур	Max	Units
DC Output Level		6.4	7.2	8	v
Quiescent Supply Current	Excludes Current in Feedback Resistors		45	80	mA
Supply Voltage Range		5		20	v
Input Resistance			150		kΩ
Bandwidth	Gain = 40 dB		100		kHz
Output Power	$\begin{split} V_S &= 13.2V, f = 1 \text{ kHz} \\ R_L &= 4\Omega, \text{ THD} = 10\% \\ R_L &= 2\Omega, \text{ THD} = 10\% \\ V_S &= 13.8V, f = 1 \text{ kHz} \\ R_L &= 4\Omega, \text{ THD} = 10\% \\ R_L &= 2\Omega, \text{ THD} = 10\% \\ V_S &= 14.4V, f = 1 \text{ kHz} \\ R_L &= 4\Omega, \text{ THD} = 10\% \\ R_L &= 2\Omega, \text{ THD} = 10\% \\ R_L &= 2\Omega, \text{ THD} = 10\% \\ R_L &= 1.6\Omega, \text{ THD} = 10\% \\ V_S &= 16V, f = 1 \text{ kHz} \\ R_L &= 4\Omega, \text{ THD} = 10\% \\ R_L &= 2\Omega, \text{ THD} = 10\% \\ R_L &= 2\Omega, \text{ THD} = 10\% \\ R_L &= 1.6\Omega, \text{ THD} = 10\% \end{split}$	4.8 7	4.3 6.5 4.8 7.4 5.2 8 9 6.5 10 10,5		
THD	$P_{O} = 2W, R_{L} = 4\Omega, f = 1 \text{ kHz}$ $P_{O} = 4W, R_{L} = 2 \Omega, f = 1 \text{ kHz}$		0.1		%
Ripple Rejection	$\begin{aligned} R_{S} &= 50\Omega, f = 100 Hz \\ R_{S} &= 50\Omega, f = 1 kHz \end{aligned}$	30	40 44		dB dB
Input Noise Voltage	$R_S = 0$, 15 kHz Bandwidth		2		μV
Input Noise Current	$R_{S} = 100 k\Omega$, 15 kHz Bandwidth		40		pA

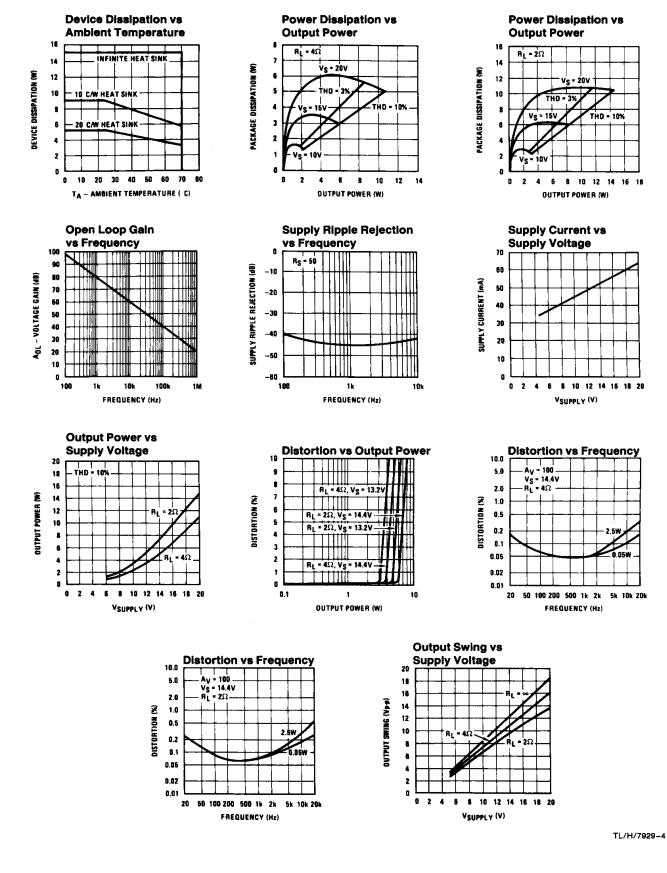
Note 1: A 1.0 resistor and 0.1 µF capacitor should be placed as close as possible to pins 3 and 4 for stability.

Note 2: The LM2002 shuts down above 25V.

Note 3: For operating at elevated temperatures, the device must be derated based on a 150°C maximum junction temperature and a thermal resistance of 4°C/W junction to case.

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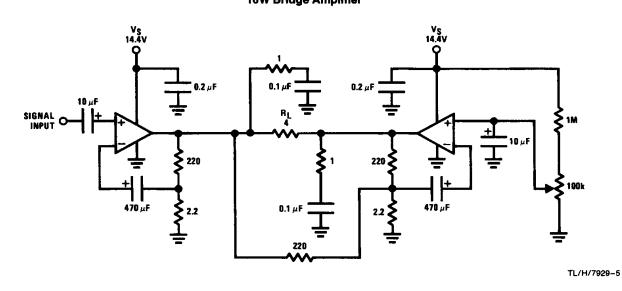


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Typical Applications (Continued)

16W Bridge Amplifier

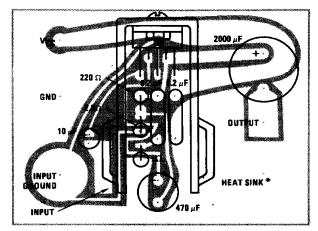


Component Layout

Single Amplifier V_S = 20V

 $R_L = 4\Omega$

LM2002/LM2002A



TL/H/7929-6

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